C ondensation energy, charge ordering and inter-layer coupling in cuprates

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The correlation between the condensation energy and the critical temperature is studied within a charge ordered superlattice bilayer model in which pairing is supported by inter-layer C oulomb energy gain (potential energy driven superconductivity). The 2D pair-condensate can be characterized by a charge ordered state with a "checkerboard" like pattern seen by scanning tunneling microscopy. The drop of the c-axis dielectric screening can be the primary source of the condensation energy at optimal doping. We note that Coulomb energy gain occurs along the c-axis, which is proportional to the measured condensation energy (U_0) and to T_c : $E_c^{3D} = 2(a_b = a_0 + 1)^2 U_0 = k_B T_c$ and is due to inter-layer charge complementarity (charge asymmetry of the boson condensate) where a_b is the coherence length of the condensate and $a_0 = 3.9A$ is the in-plane lattice constant. The static c-axis dielectric constant c_c is calculated for various cuprates and compared with the available experimental data. PACS numbers: 74.20.-z, 74.25.-q, 74.72.-h

D espite the enorm ous am ount ofe ort spent in the last decades in resolving the fundam entalphysics behind high tem perature superconductivity (HTSC) the mechanism is still puzzling [1]. It is more or less generally accepted now that the conventional electron-phonon pairing mechanism cannot explain cuprate superconductivity, because as high a transition temperature as 164K (the record $T_{\rm c}$ up to now [2]) cannot be explained by the energy scale of lattice vibrations without leading to lattice instability [1]. It is, however, already well established that much of the physics related to HTSC is in 2D nature, one of the basic questions to be answered still in the future is whether HTSC is a strictly 2D phenomenon or should be described by a 3D theory including all the 2D features of superconductivity.

The system atic dependence of the transition temperature T_c on the c-axis structure and, in particular, on the num ber of C uO 2 planes in multilayer blocks are strongly in favour of the 3D character of HTSC. Variation of the thickness of ultrathin articial HTSC compounds leads to the signi cant change of T_c supporting the importance of IL coupling in cuprates [3]. It has also been shown recently that the c-axis transport of the hole-content to the doping site in the charge reservoir in the normal state (NS) of cuprates may be important in uderstanding HTSC [4]. Despite of the signi cantam ount of published works which support the importance of the 3D character of HTSC 2D theories rule the literature in the last years [1]. This is partly due to the failure of the inter-layer (IL) tunneling model of Anderson [5,6] which was the prom inant 3D theory of HTSC. A nother reason could be that no sraigthforward dependence of Tc can be seen on the IL distance and on other 3D param eters of cuprates. Therefore the 3D character of HTSC is more complicated and needs m ore theoretical and experim entalwork in the future.

In this paper we propose a simple phenomenologicalmodel for explaining the 3D character of HTSC in cuprates supported by calculations. We would like to study the magnitude of direct Coulomb interaction between charge ordered square superlattice layers as a possible source of pairing interaction. Our intention is to understand HTSC within the context of an IL Coulombmediated mechanism. The LL charging energy we wish to calculate depends on the L spacing (d), the L dielectric constant c, the hole content p and the size of the superlattice. A large body of experim ental data are collected which support our model. A consistent picture is emerged on the basis of the careful analysis of this data set. Finally we calculate the static c-axis dielectric constant c (that is normal to the ab-plane) for various cuprates which are compared with the available experim ental observations.

W e propose to examine the following charge ordered superlattice m odel of pair condensation: A pair of charge carriers (2e) can in principle be distributed over 2=0:16 = 12:5 C uO 2 unit cells in a square lattice layer if the 2e pair is composed of the optimal hole content po 0:16=C uO₂ at optim aldoping [7]. However, allowing the phase separation of hole-anti-hole pairs, every second unit cell is occupied by 0:16e (anti-hole), and the rest is empty (holes, +0:16e), therefore we have 25 unit cells for a condensed pair of charge carriers (FIG 1, that is the unit lattice of the pair condensate in the 5 5 supercellm odel). Therefore, $2p_0 = 0.32e$ hole charge condenses to every second hole forming anti-hole sites. The 25 lattice sites provide the hole content of 25 0:16e = 4e and therefore 2e excess charge in the anti-hole sites. The other 2e charge is used for neutralizing the holes at the anti-hole sites. In other words a Cooper wave-function can be distributed on a 5 5 superlattice with a node of 0:16e in every anti-hole site. The remarkable feature is that

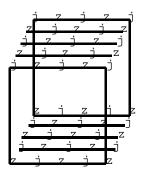


FIG. 1. The charge ordered state of the hole-anti-hole condensate in the $4a_0$ — $4a_0$ charge ordered bilayer superlattice m odel. Note the charge asymmetry between the adjacent layers. The bilayer can accommodate a pair of boson condensate (4e). The inter-layer charge complementarity of the charge ordered state is crucial for getting inter-layer C oulomb energy gain.

the size of the 5 5 condensate (four lattice spacings, $4a_0$ 15:5A) is comparable with the measured small coherence length $_{ab}$ of single-layer cuprates ($_{ab}$ 10A to 20A) [8]. $_{ab}$ can directly be related to the characteristic size of the wave-pocket of the local Cooper pair (coherence area) [8]. The charge ordered superlattice bilayer (COSB) model can in principle be applied not only for p_0 0:16e but also for the entire doping regime.

IL Coulom b energy gain occurs only in that case when holes in one of the layers are in proxim ity with anti-holes in the other layer (FIG 1, IL electrostatic complementarity, bilayer 5 5 ($4a_0$ $4a_0$) m odel). An important feature is then that the boson condensate can be described by an IL charge asymmetry. The IL coupling of the boson-boson pairs in the bilayer 5 5 m odel naturally suggests the e ective m ass of charge carriers m as it was found by measurements [17]. The 5 5 model can be generalized to represent a N N coherence area where N is the real space periodicity of the superlat-N superlattice model the hole and tice. In the N anti-hole partial charges at each CuO2 lattice sites are 4e=N² [16]. Im portant to note that the charge sum e rule holds for the characteristic bilayer with a coherence area $\int_{i}^{P} \int_{i}^{N^{2}} q_{i}^{ahole} = 4e \text{ where } q_{i}^{ahole} \text{ is the partial}$ anti-hole charge at the ith anti-hole lattice site. In other words a pair of a boson condensate can be accompanied within a COSB depicted in FIG 1.

Im portant consequence of the model outlined in this paper is that the condensation energy (U_0) of the SC state can be calculated. We will show here that within our model the primary source of U_0 is the net energy gain in IL Coulomb energy occurs due to the asymmetrical distribution of the condensed hole-charge in the adjacent layers (see FIG 1) below T_{c} .

Per de nition U_0 is the free energy di erence of the norm alstate and the superconducting state,

$$U_0 E^{ab} + E_c^{IL}$$
: (1)

Tha ab-plane contribution to the SC condensation energy E^{ab} is expected to be negligible at optimal doping. That is because our Coulomb energy calculations indicate that the ab-plane Coulomb energy in the NS and in the SC state are nearly equal and therefore the ab Coulomb energy contribution to U_0 E_c^{ab} 0 and also the kinetic energy of the pair-condensate E_{kin}^{ab} is much smaller by several order of magnitude then IL coupling. The elective Coulomb interaction between spinless point-charges may be approximated by the expression $V_{\rm eff}(r) = e^2 = (4_{-0} \ _{\rm c} r)$, where $_{\rm C}$ takes into account phenomenologically the dielectric screening elect of the IL dielectric medium and conned hole charge [16]. For instance we get for the prototypical 5 5 lattice 1.2 10 20 J ab-Coulomb energy both for the NS

1.2 10^{-20} J ab-C oulom b energy both for the NS and for the SC COS using a simple point charge model for calculating the C oulom b energy. The details of this calculation can can found in ref. [16]. The calculated ab-kinetic energy of the 5 5 codensate is 1.1 10^{-29} J if we use the very simple formula ("electron in a box")

$$T_{kin}^{ab} = \frac{h^2}{2m} = \frac{2e}{\frac{2}{ab}c};$$
 (2)

where $_{\rm C}$ is the c-axis coherence length. The IL C oulom b interaction (attraction) E $_{\rm C}^{\rm IL}$ $1.3\,$ 10 21 J for the 5 5 bilayer. It must be emphasized, however, that away from optimal doping the C oulomb energy of the condensate might a ect the magnitude of the condensation energy. The abrupt jump of the measured condensation energy U $_0$ seen in the slightly overdoped regime [22] can be attributed to the increased E $^{\rm ab}$ contribution to U $_0$.

In this article we restrict our study, however, to optimal doping and the study of the doping dependence of U $_0$ is planned in the near future. The main contribution to U $_0$ is then the IL energy gain $E_{\rm c}^{\rm IL}$ in the SC state can be given as follows,

$$U_0 = \mathcal{E}_c^{\text{IL;NS}} = \mathcal{E}_c^{\text{IL;SC}} \dot{\mathcal{F}}$$
 (3)

where E $_{\rm c}^{\rm \,IL\,;\!N\,\,S}$ and E $_{\rm c}^{\rm \,IL\,;\!S\,C}$ are the IL C oulomb energy in the NS and in SC state. We can further simplify Eq. (3) if the NS contribution to Eq. (3) is $E_c^{\,\mathrm{IL}\,;\mathrm{N}\,\mathrm{S}}$ holds if IL coupling is screened e ectively in the NS (large density of the hole content in the IL space, large (NS)). Again, if we assum e $_{c}$ 33, we get $E_{c}^{\text{IL};NS}$ +2 10 18 J (12:3 eV) for a charge ordered 5 5 lattice which would be an extraordinarily large value for the IL Coulomb repulsion. Assuming, however, c 10000, we get the m ore realistic C oulom b repulsion of E $_{\text{c}}^{\text{IL}; \text{N S}}$ + 10 22 J. Indeed there are measurements for cuprates which indicate large $_{\rm C}$ in the NS in the range of 10^3 to 10^5 [27]. Extraordinarily large dielectric constant has also been found recently in perovskite materials [12]. Anyhow the "relaxation" of the huge IL Coulomb repulsion in holedoped cuprates in the NS can not easily be understood without the consideration of a large c. Nevertheless experim entalm easurem ents and theoretical speculations

TABLE I. The calculated coherence length of the pair condensate given in a_0 using the experim ental condensation energies of various cuprates and Eq. (6) at optimal doping.

	T _c (K)	k _B T _c (m eV)	U ₀ (eV=u:c:)	calc (a0)	exp (a ₀)
B i2201	20	1.6	10 ^a	8	
LSCO	39	2.5	21 ^b	7	5 8 ^c
T 12201	85	7	100 20 ^d	5	
H g1201	95	7.8	80 107 ^e	5	5 ^f
YBCO	92	7.5	110 ^g	3	3 4 ^h
B i 2212	89	7.3	95 ^g	3 4	4 6 ⁱ

a₀ 3:88A, U₀ is the measured condensation energy of various cuprates in eV per unit cell at optim aldoping. ^a from [28], ^b U₀ 2 J/m ol from [18,19], ^c from [8], ^d [30], ^e U₀ 12 16 m J/g from [20,31] and a_b from [21], ^d U₀ 11 J/m ol from [22], ^e U₀ 10 J/m ol from [22], ^f from [21], ^g from [22], ⁱ from recent measurements of W ang et al., a_b 23A (5 6a₀) [10], from STM images of ref. [14] a_b 4a₀, ^h from [8], ^{calc} is calculated according to Eq. (6) and is also given in Table I and ^{exp} a_b is the measured in-plane coherence length given in a₀ 3:9A. The notations are as follows for the compounds: Bi2201 is Bi₂Sr₂CuO₆₊, LSCO (La_{1:85}Sr_{0:15}CuO₄), Ti2201 (Tl₂Ba₂CuO₆), Hg1201 (HgBa₂CuO₄₊), YBCO (YBa₂CuO₇) and Bi2212 is Bi₂Sr₂CaCuO₈₊.

suggest that $_{\rm c}$ in cuprates and in other materials with perovskite structure is strongly temperature and doping dependent [11]. The sharp decrease of $_{\rm c}$ below $T_{\rm c}$ should also be explained within our bilayer model by the pair-condensation of the hole-content to the sheets. This is what can be seen in the c-axis optical spectra of cuprates [6,24]. The lack of the c-axis plasma edge in the NS is an obvious experimental evidence of the strong temperature dependence of $_{\rm c}$. Then we have

$$2(n + 1)N^{2}U_{0} = E_{c}^{IL;SC};$$
 (4)

where $E_c^{\rm IL}$; SC is the Coulomb energy gain in the SC state. U_0 is the experimental condensation energy given per unit cell. Eq. (4) is generalized form ultilayer cuprates introducing n. For single layer cuprates n=0, for bilayers n=1, etc.

Inter-layer C oulom b coupling can be a natural source of the condensation energy and of H T SC . C heckerboard-like charge pattern (COS) seen experimentally [14,15] directly leads to IL energy gain and to potential energy driven condensation energy if the hole-anti-hole charge pattern is asymmetry cally condensed to the adjacent layers (FIG 1). Assuming that thermical equilibrium occurs at $T_{\rm c}$ for the competing charge ordered phases of the NS and the SC state the following equation for the condensation energy can be formulated using Eq. (4),

$$2(n + 1)N^{2}U_{0}$$
 $2(n + 1)$ $\frac{ab}{a_{0}} + 1$ U_{0} $k_{B} T_{c}$; (5)

where k_B is the Boltzm ann constant.

At a rst look this formula seems to be unusual because of the dependence of the condensation energy on

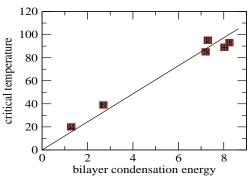


FIG.2. The critical tem perature (K) at optim aldoping as a function of the bilayer condensation energy (2 (n + 1)N $^2 \text{U}_0$, m eV) using Eq.(5). The straight line is a linear t to the data. The slope of the linear t is k_B which is a strong evidence of Eq.(5).

 $T_{\rm c}$. The available measurements of the condensation energy on various cuprates show no correlation of U_0 with the critical temperature. One of the important goals of this paper, however, to show that correlation can indeed be found with $T_{\rm c}$ if $T_{\rm c}$ is plotted against $2\,(n+1)N^2U_0$ (the bilayer condensation energy, FIG 2). In other words the condensation energy of the COSB system shows correlation with $T_{\rm c}$. In order to test the validity of Eq. (5) we estimate the coherence length of the pair condensate using Eqs. (5) and using only experimental data,

The results are given in Table I as $_{\rm ab}^{\rm calc}$ and compared w ith the availablem easured exp ab . The agreem ent is excellent which strongly suggests that Eq. (6) should also work for other cuprates. The validity of Eq. (5) is clearly clari ed in FIG 2 using mostly experimental information for $_{\rm ab}$, $T_{\rm c}$ and $U_{\rm 0}$ (values are given in Table I.). For T 12201 no measured ab is found in the literature, therefore the estimated ab is used (given in Table I.). We will show that using this estimated value of N = 6(ab)predict $_{\rm c}$ in nice agreem ent with optical measurem ents for T12201. Rem arkable feature of FIG 2 is that the slope of the linear t to the measured data points is precisely k_B which supports Eq. (5). The underlying physics of HTSC seems to be re ected by Eq. (5): the equation couples the basic observable quantities T_c ; U_0 and ab. We predict for the multilayer H g-cuprates, H g1212 ($T_c = 126$ K) and Hg1223 ($T_c = 135 \text{ K}$) the condensation energies 146 and 117 eV/u.c. (ab 4a₀ [21]), respectively using Eq. (5).

The expression Eq. (5) leads to the very simple form ula for the critical temperature using Eq. (4) and a simple Coulomb expression for the IL coupling energy $E_c^{\,{\rm IL}\,;S\,C}$ [16] (T_c $k_B^{\,{\rm IL}\,;S\,C}$)

TABLE II. The calculated dielectric constant $_{\text{c}}$ using Eq.(8) in various cuprates at the calculated coherence length $_{\text{ab}}$ of the charge ordered state given in Table I.

	d (A)	T _c (K)	calc (a ₀)	С	exp c
B i2201	12.2	20	8	9.9	12ª
LSCO	6.65	39	7	11.3	23 3;13:5 ^b
H g1201	9.5	95	5	6.5	
T 12201	11.6	85	5	13.0	11.3°
YBCO	8.5	93	3	19.4	23 . 6 ^d

where $_{ab}^{calc}$ is the estim ated in-plane coherence length given in $_{a0}$ 3:9A unit. d is the C uO $_{2}$ plane to plane inter-layer distance in A, T $_{c}$ is the experime ntal critical temperature. $_{c}$ is from Eq. (8). $_{c}^{exp}$ are the measured values obtained from the following references: $_{c}^{a}$ [25], $_{c}^{b}$ [26], or from rejectivity measurements [30], $_{p}$ 55cm $_{c}^{1}$ [33], $_{c}$ 3 m [31], $_{c}^{c}$ from [30], $_{d}^{d}$ from rejectivity measurements: $_{p}$ 60cm $_{c}^{1}$ [33], $_{c}$ 0:9 m [13].

$$T_{c}(N;d;_{c}) = \frac{e^{2}}{4 \cdot {_{0}}_{c}k_{B}} X^{2} X^{1} X^{2} \frac{X^{1}}{2} \frac{q_{i}^{(n)}q_{j}^{(m)}}{r_{ij}^{(n,m)}}$$
(7)

where $r_{ij}^{(n,\text{rm })}$ is the inter-point charge distance and $r_{ij}^{(n,\text{rm })}$ d_{IL} , where d_{IL} is the IL distance (C uO $_2$ plane to plane, i f j). n;m represent layer indexes (n f m). First the summation goes within the bilayer up to N 2 then the IL C oulomb interaction of the basal bilayer are calculated with other layers along the c-axis in both direction (n = 1;2) [16]. N $_1$ is the number of layers along the c-axis. When N $_1$! 1, bulk T $_c$ is calculated. T $_c$ can also be calculated for thin $lm\ s\ when\ N_1$ is nite. $_c$ can also be derived

$$c = \frac{e^{2}}{4 + {_{0}k_{B}T_{c}}} \frac{X^{2} + X^{1} + X^{2}}{{_{n=1m=2} + ij}} \frac{q_{i}^{(n)} q_{j}^{(m)}}{r_{ij}^{(n,m)}}$$
(8)

where a c-axis average of $_{\rm C}$ is computed when N $_1$! 1. The calculation of the c-axis dielectric constants $_{\rm C}$ m ight provide further evidences for Eq. (5) when compared with the measured values [11,26]. In Table II we have calculated the static dielectric function $_{\rm C}$ using Eq. (8) and compared with the experimental impedance measurements [27,26]. $_{\rm C}$ can also be extracted from the c-axis optical measurements using the relation [30] $_{\rm C}(!)=_{\rm C}(1)$ $c^2=(!\frac{2}{p}-\frac{2}{c})$, where $_{\rm I}$ and $!_{\rm p}$ are the high-frequency dielectric constant and the plasma frequency, respectively [34]. c and $_{\rm C}$ are the speed of light and the c-axis penetration depth. At zero crossing $_{\rm C}(!)=0$ and $!_{\rm p}=c=(\frac{1}{c}\frac{1}{c}(1))$. U sing this relation we predict for the single layer H g1201 the low plasma frequency of $!_{\rm p}=8$ cm 1 using $_{\rm C}=_{\rm C}(1)=6.5$ (Table II) and $_{\rm C}=8$ m [31].

If the physical picture derived from our model is correct, it should be a guide for further experimental studies aim ing to improve SC in cuprates or in other materials. This can be done by tuning the IL distance and $_{\rm c}$ in these materials. The application of this model to other

class of HTSC m aterials, such as fullerides or M gB $_{\rm 2}$ is expected to be also e ective.

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